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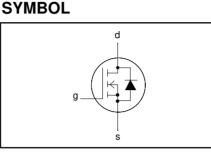
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



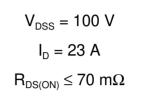
PHP23NQ10T, PHB23NQ10T PHD23NQ10T

FEATURES

- 'Trench' technology
- · Low on-state resistance
- · Fast switching
- · Low thermal resistance



QUICK REFERENCE DATA



GENERAL DESCRIPTION

N-channel enhancement mode field-effect power transistor in a plastic envelope using 'trench' technology.

Applications:-

- d.c. to d.c. converters
- switched mode power supplies
- T.V. and computer monitor power supplies

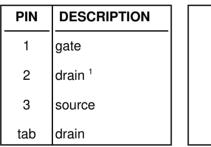
The PHP23NQ10T is supplied in the SOT78 (TO220AB) conventional leaded package. The PHB23NQ10T is supplied in the SOT404 (D²PAK) surface mounting package. The PHD23NQ10T is supplied in the SOT428 (DPAK) surface mounting package.

PINNING

SOT78 (TO220AB)

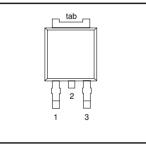
SOT404 (D²PAK)

SOT428 (DPAK)



tab

tab 2 1 3



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DSS}	Drain-source voltage	T _i = 25 °C to 175°C	-	100	V
V _{DGR}	Drain-gate voltage	$T_{i} = 25 \text{ °C to } 175 \text{ °C}; R_{GS} = 20 \text{ k}\Omega$	-	100	V
V _{GS}	Gate-source voltage		-	± 20	V
	Continuous drain current	$T_{mb} = 25 \ ^{\circ}C; V_{GS} = 10 \ V$	-	23	A
5		$T_{mb} = 100 \ ^{\circ}C; V_{GS} = 10 \ V$	-	16	A
I _{DM}	Pulsed drain current	$T_{mb} = 25 \degree C$	-	92	A
PD	Total power dissipation	$T_{mb} = 25 \degree C$	-	100	W
T _j , T _{stg}	Operating junction and storage temperature		- 55	175	°C

¹ It is not possible to make connection to pin:2 of the SOT404 or SOT428 packages.

PHP23NQ10T, PHB23NQ10T PHD23NQ10T

AVALANCHE ENERGY LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
/.0	energy	Unclamped inductive load, $I_{AS} = 14 \text{ A}$; $t_p = 100 \ \mu\text{s}$; T_j prior to avalanche = 25°C; $V_{DD} \le 25 \text{ V}$; $R_{GS} = 50 \ \Omega$; $V_{GS} = 10 \text{ V}$; refer to fig:15	-	93	mJ
I _{AS}	Peak non-repetitive avalanche current	, , , , , , , , , , , , , , , , , , ,	-	23	A

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Thermal resistance junction to mounting base Thermal resistance junction	SOT78 package, in free air	-	- 60	1.5	K/W K/W
R _{th j-a}	to ambient	SOT404 package, pcb mounted, minimum footprint	-	50 50	-	K/W

ELECTRICAL CHARACTERISTICS

 T_i = 25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{(BR)DSS}	Drain-source breakdown	$V_{GS} = 0 \text{ V}; \text{ I}_{D} = 0.25 \text{ mA};$	100	-	-	V
	voltage	$T_j = -55^{\circ}C$	89	-	-	V
$V_{GS(TO)}$	Gate threshold voltage	$V_{DS} = V_{GS}; I_D = 1 \text{ mA}$	2	3	4	V
		$T_{j} = 175^{\circ}C$ $T_{i} = -55^{\circ}C$	1	-	-	V V
Б	Drain course on state		-	- 49	6 70	ν mΩ
R _{DS(ON)}	Drain-source on-state	$V_{GS} = 10 \text{ V}; I_D = 13 \text{ A}$ $T_i = 175^{\circ}\text{C}$	-	132	189	mΩ
I _{GSS}	Gate source leakage current	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0 \text{ V}$	_	10	100	nA
I _{DSS}	Zero gate voltage drain	$V_{\rm DS} = 100 \text{ V}; V_{\rm DS} = 0 \text{ V}$	-	0.05	100	μA
USS	current	$T_{j} = 175^{\circ}C$	-	-	500	μA
Q _{g(tot)}	Total gate charge	$I_{D} = 23 \text{ A}; V_{DD} = 80 \text{ V}; V_{GS} = 10 \text{ V}$	-	22	-	nC
Q _{gs}	Gate-source charge		-	5	-	nC
$\tilde{Q_{gd}}$	Gate-drain (Miller) charge		-	10	-	nC
t _{d on}	Turn-on delay time	$V_{DD} = 50 \text{ V}; \text{ R}_{D} = 2.2 \Omega;$	-	8	-	ns
t _r	Turn-on rise time	$V_{GS} = 10 \text{ V}; \text{ R}_{G} = 5.6 \Omega$	-	39	-	ns
t _{d off}	Turn-off delay time	Resistive load	-	26	-	ns
t _f	Turn-off fall time		-	24	-	ns
L _d	Internal drain inductance	Measured tab to centre of die	-	3.5	-	nH
L _d	Internal drain inductance	Measured from drain lead to centre of die	-	4.5	-	nH
-		(SOT78 package only)				
L _s	Internal source inductance	Measured from source lead to source	-	7.5	-	nH
		bond pad				
C _{iss}	Input capacitance	V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz	-	890	1187	рF
Coss	Output capacitance		-	139	167	pF
C _{rss}	Feedback capacitance		-	83	109	рF

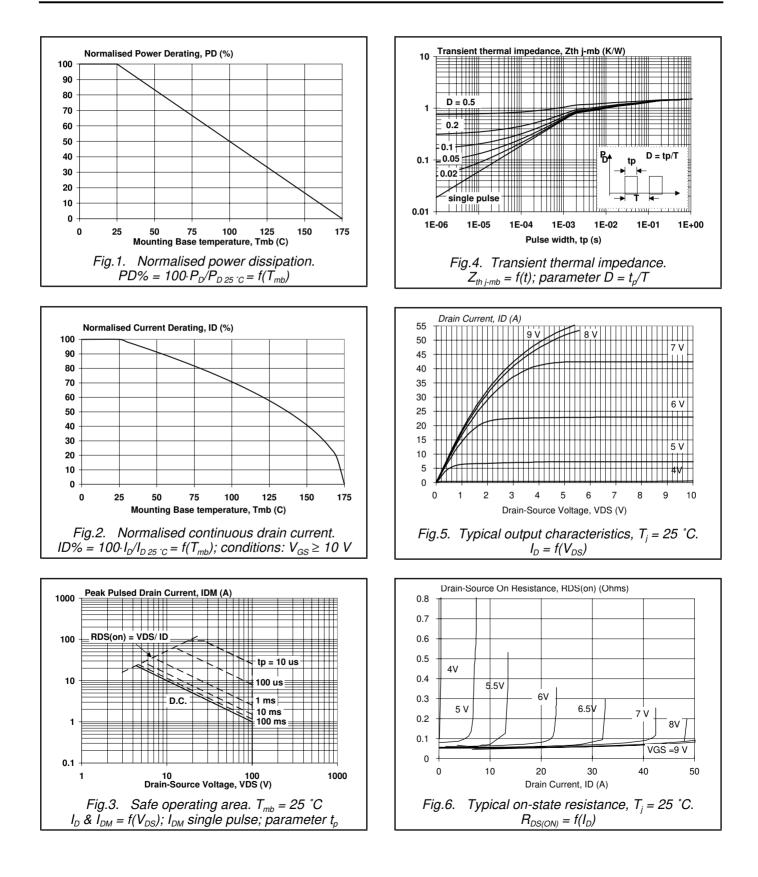
PHP23NQ10T, PHB23NQ10T PHD23NQ10T

REVERSE DIODE LIMITING VALUES AND CHARACTERISTICS

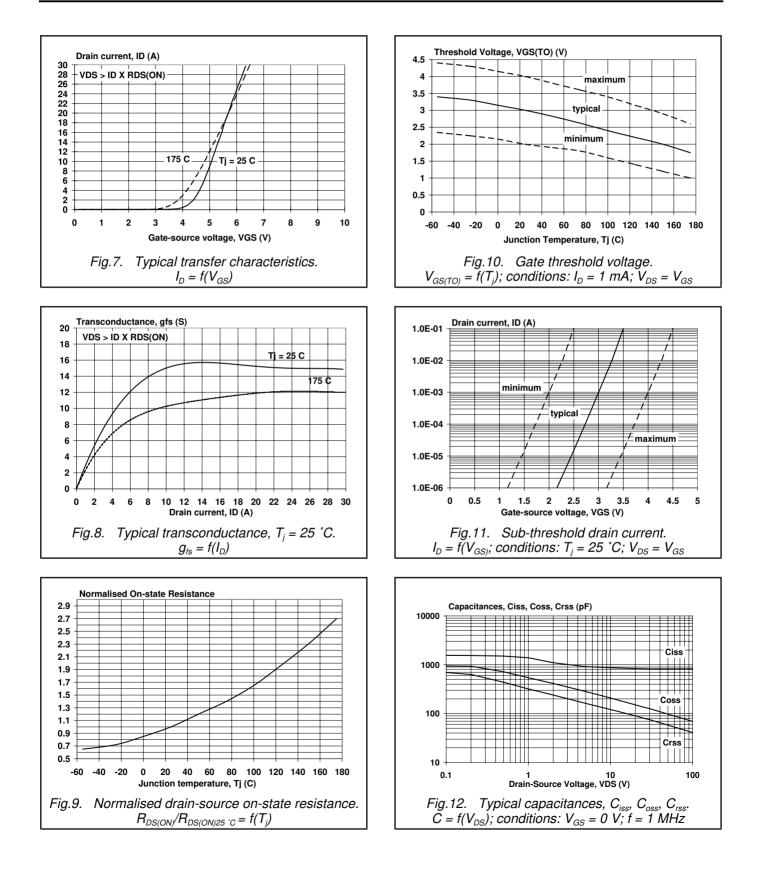
 $T_i = 25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
3	Continuous source current (body diode)		-	-	23	A
I _{SM}	Pulsed source current (body diode)		-	-	92	А
V_{SD}	Diode forward voltage	$I_{F} = 11 \text{ A}; V_{GS} = 0 \text{ V}$	-	0.9	1.2	V
t _{rr} Q _{rr}	Reverse recovery time Reverse recovery charge	$ I_{F} = 11 \text{ A}; -dI_{F}/dt = 100 \text{ A}/\mu\text{s}; \\ V_{GS} = 0 \text{ V}; \text{ V}_{R} = 25 \text{ V} $	-	64 120	-	ns nC

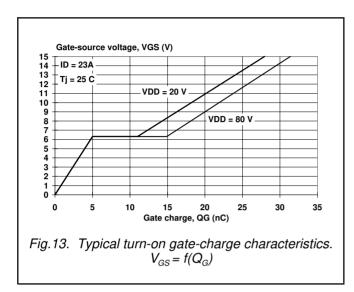
PHP23NQ10T, PHB23NQ10T PHD23NQ10T

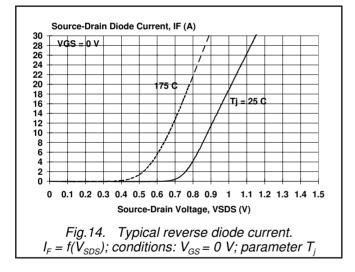


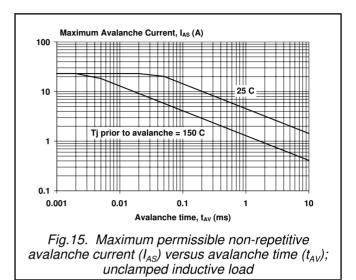
PHP23NQ10T, PHB23NQ10T PHD23NQ10T



PHP23NQ10T, PHB23NQ10T PHD23NQ10T

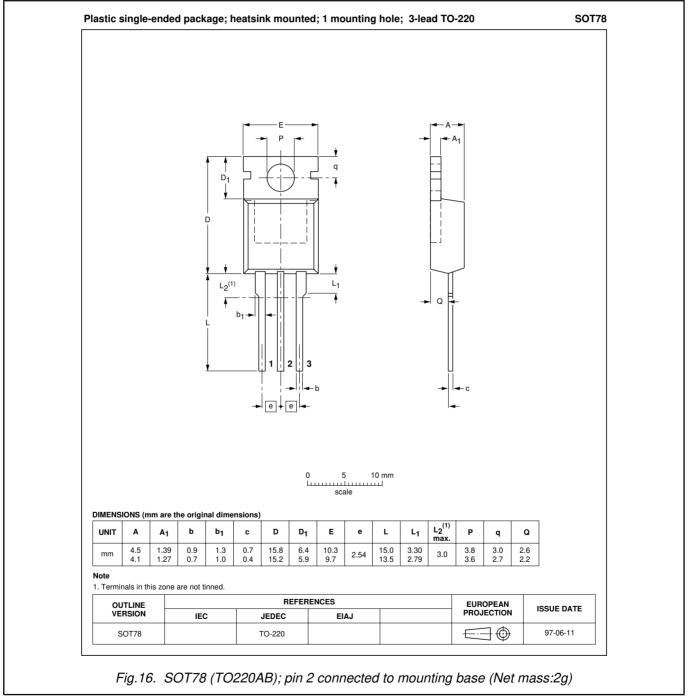






PHP23NQ10T, PHB23NQ10T PHD23NQ10T

MECHANICAL DATA

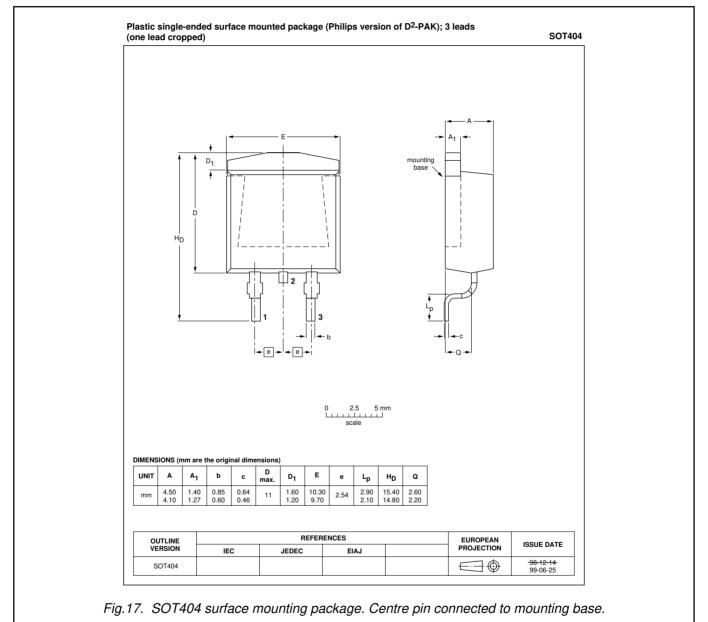


Notes

- 1. This product is supplied in anti-static packaging. The gate-source input must be protected against static discharge during transport or handling.
- 2. Refer to mounting instructions for SOT78 (TO220AB) package.
- 3. Epoxy meets UL94 V0 at 1/8".

PHP23NQ10T, PHB23NQ10T PHD23NQ10T

MECHANICAL DATA



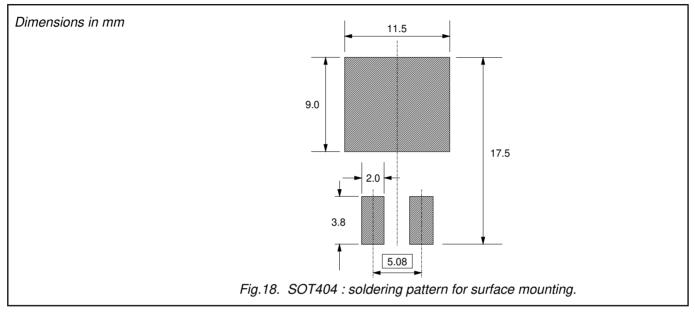
Notes

1. This product is supplied in anti-static packaging. The gate-source input must be protected against static discharge during transport or handling.

- 2. Refer to SMD Footprint Design and Soldering Guidelines, Data Handbook SC18.
- 3. Epoxy meets UL94 V0 at 1/8".

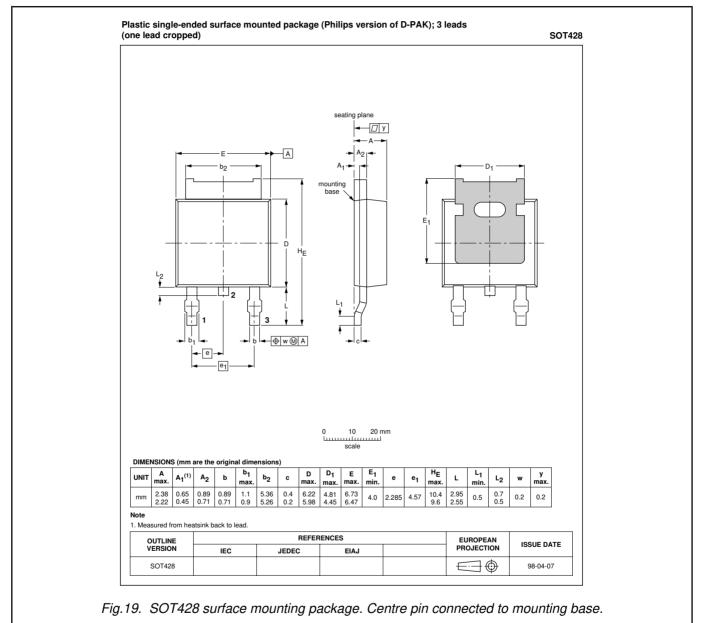
PHP23NQ10T, PHB23NQ10T PHD23NQ10T

MOUNTING INSTRUCTIONS



PHP23NQ10T, PHB23NQ10T PHD23NQ10T

MECHANICAL DATA



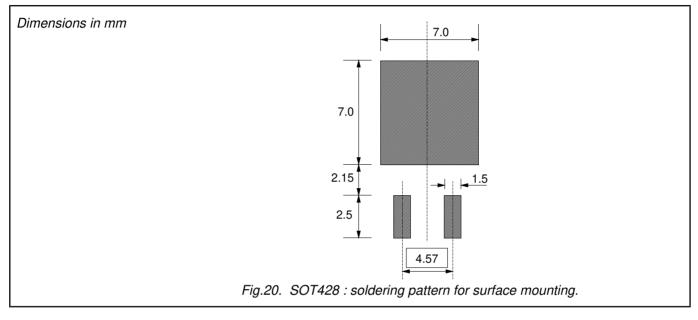
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PHP23NQ10T, PHB23NQ10T PHD23NQ10T

MOUNTING INSTRUCTIONS



PHP23NQ10T, PHB23NQ10T PHD23NQ10T

DEFINITIONS

Data sheet status				
Objective specification This data sheet contains target or goal specifications for product development.				
Preliminary specification This data sheet contains preliminary data; supplementary data may be published late				
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information Where application information is given, it is advisory and does not form part of the specification.				
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